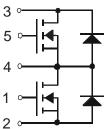


Advance Technical Information

PolarHV™ HiPerFET **N-Channel Power MOSFET Phase Leg Topology**

FMM22-05PF



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4	· +	-
1 4		
2	_''	

	I _{D25}	=	13A
	R _{DS(on)}	≤	270m $Ω$
+	t _{rr(max)}	<	200ns
—			

ISOPLUS i4-Pak™

 $\mathbf{V}_{\mathrm{DSS}}$

71 Isolated Tab

Symbol	Test Conditions	Maximum Ratings		
T,		-55 +150	°C	
T _{JM}		150	°C	
T _{stg}		-55 +150	°C	
V _{ISOLD}	$50/60H_{Z}$, RMS, t = 1min, leads-to-tab	2500	~V	
T,	1.6mm (0.062 in.) from case for 10s	300	°C	
T _{SOLD}	Plastic body for 10s	260	°C	
F _c	Mounting force	20120 / 4.527	N/lb.	

Symbol Test Conditions Maximum Ratings $\mathbf{V}_{\mathrm{DSS}}$ $T_{\perp} = 25^{\circ}C$ to $150^{\circ}C$ 500 ٧ 500 $T_J = 25^{\circ}C$ to 150°C, $R_{GS} = 1M\Omega$ V_{DGR} $\mathbf{V}_{\mathrm{gss}}$ Continuous ± 30 $\mathbf{V}_{\mathrm{GSM}}$ Transient ± 40 $T_{c} = 25^{\circ}C$ 13 Α I_{D25} $T_{c} = 25^{\circ}C$, pulse width limited by T_{IM} 55 Α I_{DM} $T_{c} = 25^{\circ}C$ 22 I Α \mathbf{E}_{as} $T_{c} = 25^{\circ}C$ 750 mJ ${\rm I_S} \ \leq {\rm I_{DM}}, \ {\rm V_{DD}} \leq {\rm V_{DSS}}, \ {\rm T_J} \leq 150^{\circ}{\rm C}$ dV/dt 10 V/ns $T_{c} = 25^{\circ}C$ 132 \mathbf{P}_{D} W

Symbol	Test Conditions	Characteristic Values			
		Min.	Тур.	Max.	
C _p	Coupling capacitance between shorted pins and mounting tab in the case		40	pF	
d_s, d_{Δ}	pin - pin	1.7		mm	
d _s ,d _A d _s ,d _A	pin - backside metal	5.5		mm	
Weight			9	g	

Features

- Silicon chip on Direct-Copper Bond (DCB) substrate
 - UL recognized package
 - Isolated mounting surface
 - 2500V electrical isolation
- Avalanche rated
- Low Q_G
- Low Drain-to-Tab capacitance
- Low package inductance

Advantages

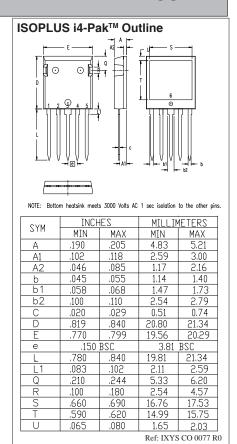
- Low gate drive requirement
- High power density
- Fast intrinsic rectifier
- Low drain to ground capacitance
- Fast switching

Applications

- DC and AC motor drives
- UPS, solar and wind power inverters
- Synchronous rectifiers
- Multi-phase DC to DC converters
- Industrial battery chargers
- Switching power supplies



Symbol (T _J = 25°C υ	Test Conditions ² unless otherwise specified)	Characteristic Value Min. Typ. Max.			ues
BV _{DSS}	$V_{GS} = 0V, I_{D} = 250\mu A$	500			V
V _{GS(th)}	$V_{DS} = V_{GS}$, $I_{D} = 1 \text{mA}$	3.0		5.0	V
l _{GSS}	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{V}$			± 100	nA
I _{DSS}	$V_{DS} = V_{DSS}$ $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			5 250	μ Α μ Α
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 11A, Note 1$			270	mΩ
\mathbf{g}_{fs}	$V_{DS} = 20V, I_{D} = 11A, Note 1$		20		S
C _{iss}			2630		pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		310		рF
C _{rss}			27		pF
t _{d(on)}	Resistive Switching Times		22		ns
t,	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 22A$		25		ns
t _{d(off)}	$R_{\rm g} = 10\Omega$ (External)		72		ns
t _f			21		ns
$Q_{g(on)}$			50		nC
Q _{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 11A$		16		nC
\mathbf{Q}_{gd}			18		nC
\mathbf{R}_{thJC}				0.95 °	C/W
R _{thCS}			0.15	0	C/W



Source-Drain Diode

Characteristic Values

T₁ = 25°C unless otherwise specified)

Symbol	Test Conditions ³	Min.	լ Тур.	Max.	
l _s	$V_{GS} = 0V$			13	Α
SM	Repetitive, pulse width limited by $T_{_{\rm JM}}$			55	Α
V _{SD}	$I_F = 22A$, $V_{GS} = 0V$, Note 1			1.5	V
t _{rr}	$I_F = 22A$, -di/dt = 100A/ μ s			200	ns
I _{RM}	$V_{R} = 100V, V_{GS} = 0V$		7.0		Α
\mathbf{Q}_{RM}	$V_{\rm R} = 100V, V_{\rm GS} = 0V$		0.7		μС

Note 1: Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2 \%$.

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated objective result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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